

DIO20721/1D/2/4

Single/Dual/Quad Channel, RRIO 10 MHz Amplifier

Features

- Rail-to-rail input and output
- 0.5 mV typical offset (V_{OS})
- Low distortion
- Gain bandwidth product: 10 MHz
- Wide supply range: 2.5 V to 5.5 V
- 620 μ A/Amplifier typical supply current
- Slew rate: 6.5 V/ μ s
- DIO20721 available in SC70-5, SOT23-5

DIO20721D available in SOT23-6

DIO20722 available in SOIC-8, MSOP-8,
DFN2*2-8, TSSOP-8 and TSOT23-8

DIO20724 available in SOIC-14, TSSOP-14

Applications

- Portable equipment
- Active filters
- Data acquisition
- Portable equipment
- Test equipment
- Broadband communication
- Process control
- Audio and video processing

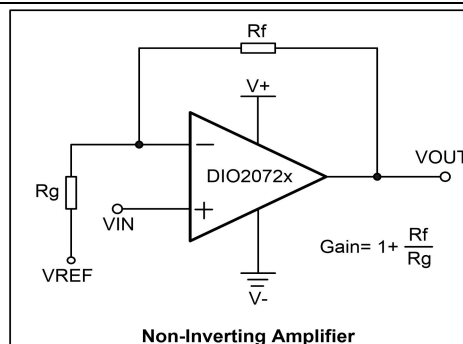
Ordering Information

Descriptions

The DIO2072x is a single/dual/quad channel, rail-to-rail I/O operational amplifier which allows low load impedances to be driven. With a 10MHz unity-gain frequency and low noise, low distortion and high output current capability, the DIO2072x provides excellent choice for high quality systems. The input common-mode voltage range includes ground, and the maximum input offset voltage is 0.5mV (guaranteed). They are also capable of comfortably driving large capacitive loads.

DIO2072x is offered in Green or RoHS package and ESD (HBM) exceeds 2kV. It is specified over the extended -40 to 125°C.

Typical Application



Order Part Number	Top Marking	RoHS	T _A	Package		
DIO20721SC5	YWXX	Green	-40 to 125°C	SC70-5	MSL3	Tape & Reel, 3000
DIO20721ST5	YWXX	Green	-40 to 125°C	SOT23-5	MSL3	Tape & Reel, 3000
DIO20721DST6	YWDK	Green	-40 to 125°C	SOT23-6	MSL3	Tape & Reel, 3000
DIO20722MP8	DIO2072	Green	-40 to 125°C	MSOP-8	MSL3	Tape & Reel, 3000
DIO20722SO8	DIO2072	Green	-40 to 125°C	SOIC-8	MSL3	Tape & Reel, 2500
DIO20722TN8	2072	Green	-40 to 125°C	DFN2*2-8	MSL3	Tape & Reel, 3000
DIO20722TP8	DIO2072	Green	-40 to 125°C	TSSOP-8	MSL3	Tape & Reel, 3000
DIO20722TST8	DTYW	Green	-40 to 125°C	TSOT23-8	MSL3	Tape & Reel, 4000
DIO20724CS14	DIO2074	Green	-40 to 125°C	SOIC-14	MSL3	Tape & Reel, 2500
DIO20724TP14	DIO2074	Green	-40 to 125°C	TSSOP-14	MSL3	Tape & Reel, 2500



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1. Pin Assignments

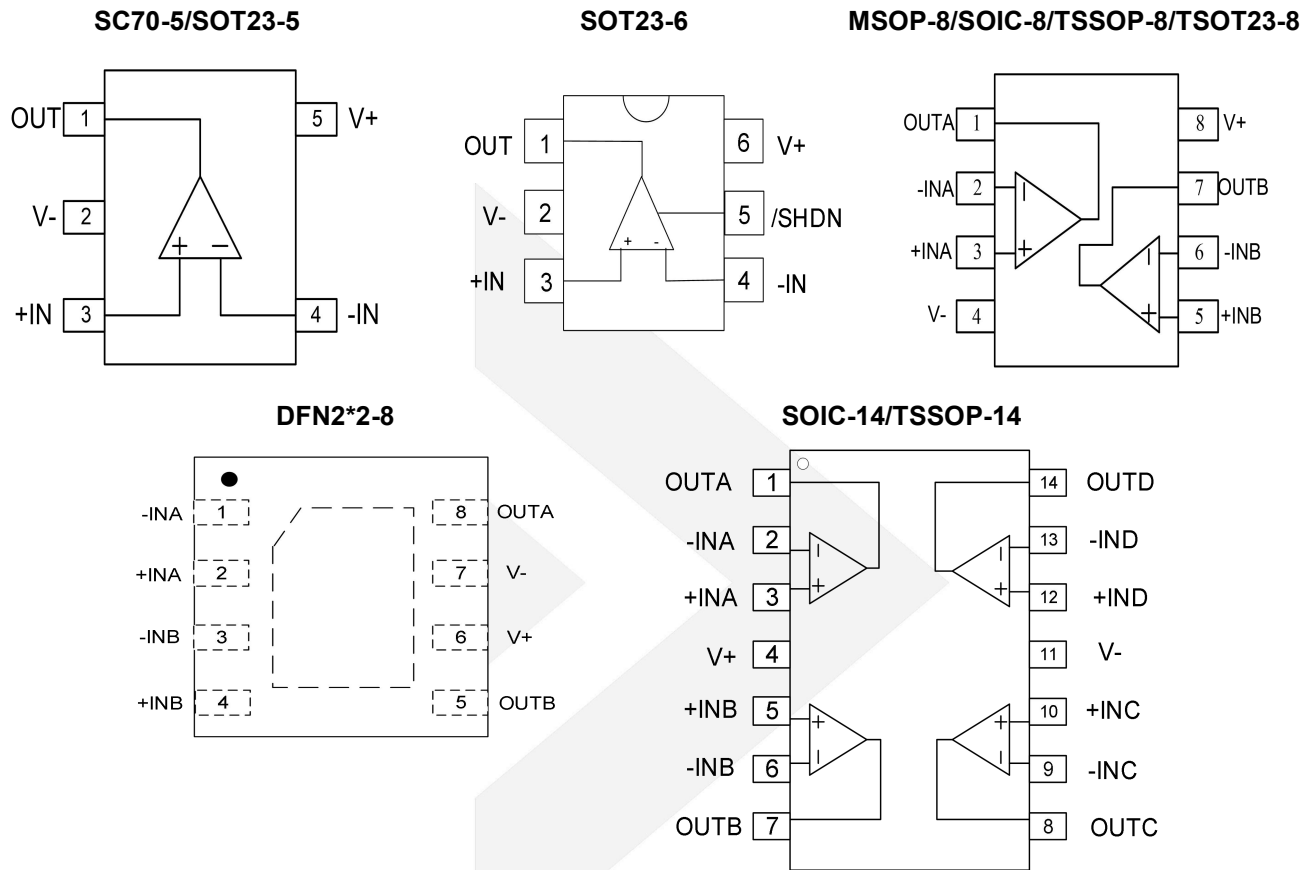


Figure 1 Top view

Pin Description

Pin Name	Description
V+	Positive supply
V-	Negative supply
+INx (+INA, +INB, +INC, +IND,)	Positive Input (channel A,B,C,D)
-INx (-INA, -INB, -INC, -IND)	Negative Input (channel A,B,C,D)
OUTx (OUTA, OUTB, OUTC, OUTD)	Output (channel A,B,C,D)
/SHDN	Active low shutdown



2. Absolute Maximum Ratings

Stresses beyond those listed under “Absolute Maximum Rating” may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other condition beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability. DIOO does not recommend exceeding them or designing to Absolute Maximum Ratings.

Parameter		Rating	Unit
Supply voltage		7	V
Input voltage		(V-)-0.5 to 7	V
Storage temperature range		-65 to 150	°C
Junction temperature		150	°C
Lead temperature range		260	°C
ESD	HBM, JEDEC: JESD22-A114	2	kV
	CDM, JEDEC: JESD22-C101	1	

3. Recommended Operating Conditions

The Recommended Operating Conditions table defines the conditions for actual device operation to ensure optimal performance to the datasheet specifications.

Parameter		Rating	Unit
Supply voltage		2.5 to 5.5	V
Input voltage		0 to 5	V
Operating temperature range		-40 to 125	°C

4. Electrical Characteristics

Typical value: $V_+ = 5\text{ V}/2.5\text{ V}$, $V_{CM} = V_+/2$, $R_L = 600\ \Omega$, $T_A = 25^\circ\text{C}$, unless otherwise specified.

Symbol	Parameter	Conditions	Min	Typ	Max.	Unit
Input characteristics						
V _{OS}	Input offset voltage	-40°C ≤ T _A ≤ 125°C, V ₊ = 2.5 V to 5 V	-5.0	0.5	5.0	mV
I _B	Input bias current	-40°C ≤ T _A ≤ 125°C, V ₊ = 2.5 V to 5 V		10		pA
I _{OS}	Input offset current	-40°C ≤ T _A ≤ 125°C, V ₊ = 2.5 V to 5 V		1.0		pA
V _{CM}	Common mode voltage range		-0.1		(V ₊) +0.1	V
CMRR	Common mode rejection ratio	-40°C ≤ T _A ≤ 125°C, V _{CM} = -0.1 to (V ₊) +0.1, V ₊ = 5 V	75	90		dB
A _{OL}	Open loop voltage gain	R _L = 600 Ω, V _o = 0.1 to (V ₊) -0.1	100	130		dB
ΔV _{OS} /ΔT	Input offset voltage drift	-40°C ≤ T _A ≤ 125°C			2.0	μV/°C
Output characteristics						
	Output voltage swing from rail	R _L = 600 Ω, -40°C ≤ T _A ≤ 125°C		0.1		V
		R _L = 10 Ω, -40°C ≤ T _A ≤ 125°C		0.015		
I _{OUT}	Output current	V ₊ = 5 V	80	85		mA
		V ₊ = 2.5 V	20	27		
	Closed loop output impedance	f = 1 MHz, G = +1, V ₊ = 5V		2.8		Ω
		f = 1 MHz, G = +1, V ₊ = 2.5V		4.4		
Power supply						
PSRR	Power supply rejection ratio		75	110		dB
I _{SHDN}	Shutdown pin current			-10		pA
I _S	Supply current per channel/amp	V ₊ = 5 V, -40°C ≤ T _A ≤ 125°C	480	620	870	μA
		V ₊ = 2.5 V, -40°C ≤ T _A ≤ 125°C	450	590	830	
I _{LEAK}	Output leakage current in shutdown	V _{SHDN} = 0 V		3.6		pA
V _{IL}	SHDN input low voltage	Disable			0.5	V
V _{IH}	SHDN input high voltage	Enable	1.1			V
Dynamic performance						
GBP	Gain bandwidth product			10.0		MHz
SR	Slew rate	G = 1, 2 V Output Step		6.5		V/μs
t _S	Setting time	G = 1, 2 V Output Step		0.25		μs
X _{talk}	Channel separation	f = 1 kHz, R _L = 10 kΩ		110		dB
	Overload recovery time	V _{IN} × Gain = V ₊		1.0		μs
Noise performance						
THD	Total harmonic distortion	f = 10 kHz, 2 V output step, R _L = 600 Ω, V ₊ = 5 V		0.04		%
e _n	Voltage noise density	f = 1 kHz, V ₊ = 5 V		28		nV/√Hz

$f = 10 \text{ kHz}$, $V_+ = 5 \text{ V}$

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5. Typical Performance Characteristics

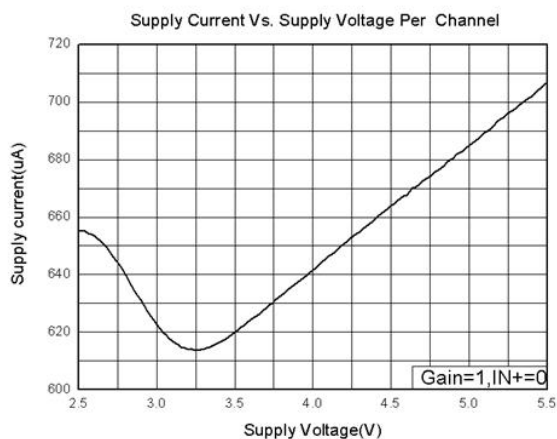


Figure 2 Supply current vs. Supply voltage per channel

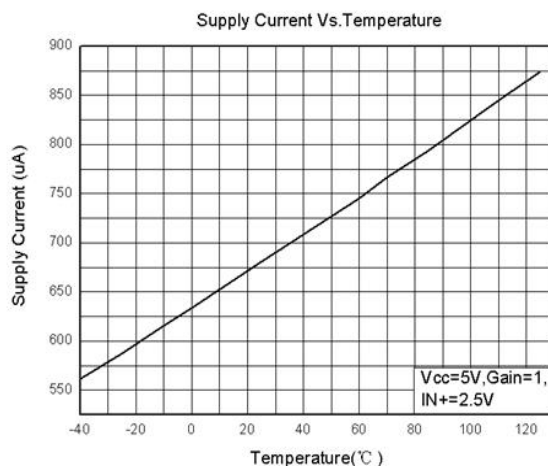


Figure 3 Supply current vs. Temperature

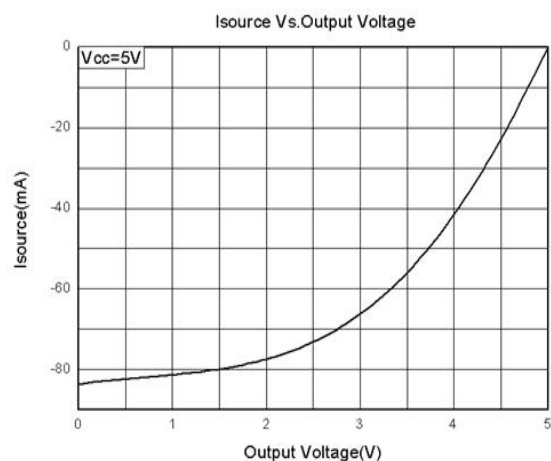


Figure 4 I_{SOURCE} vs. Output voltage

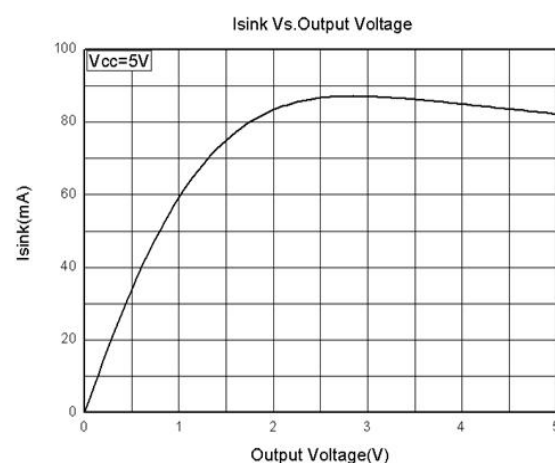


Figure 5 I_{SINK} vs. Output voltage

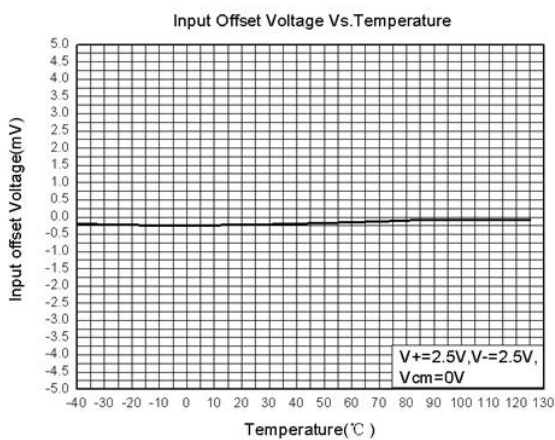


Figure 6 Input offset voltage vs. Temperature

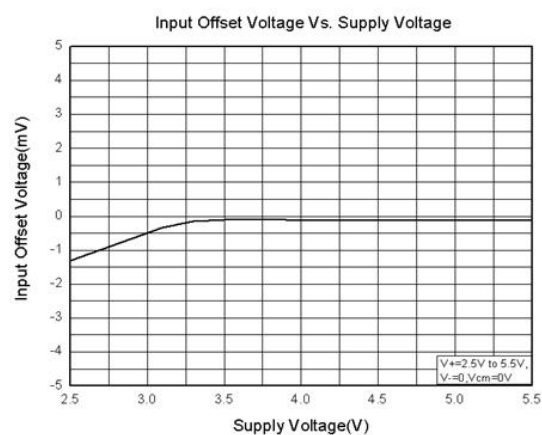


Figure 7 Input offset voltage vs. Supply voltage

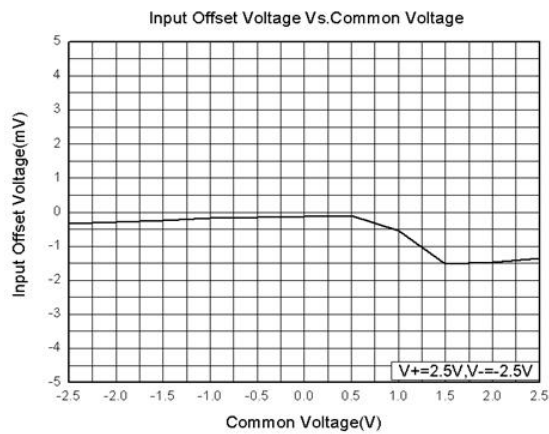


Figure 8 Input offset voltage vs. Common voltage

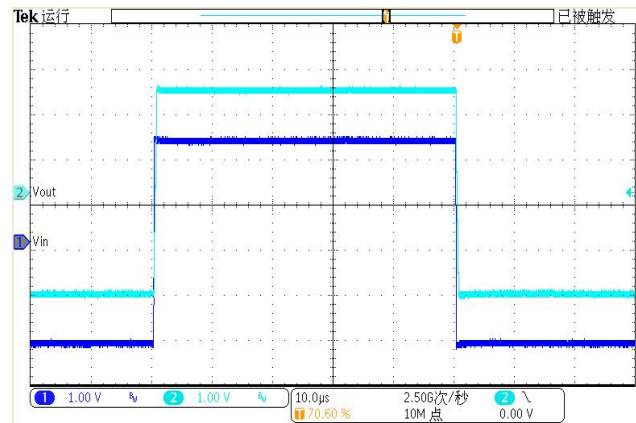
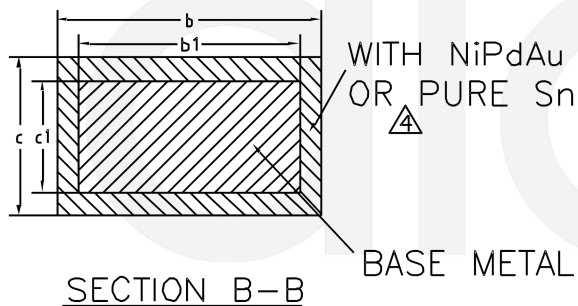
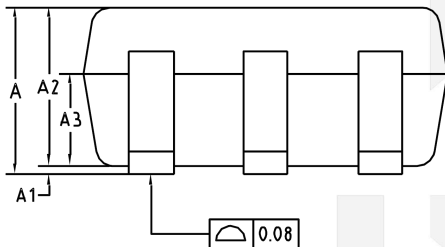
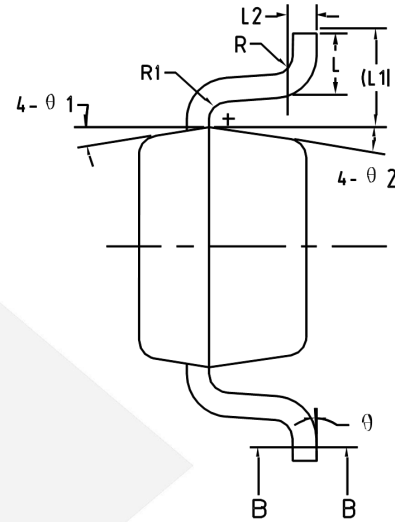
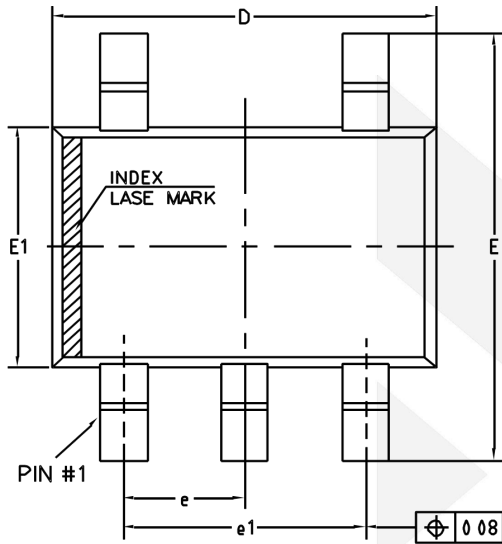


Figure 9 Large-signal response ($V^+ = 5\text{ V}$, $R_L = 1\text{ M}\Omega$)

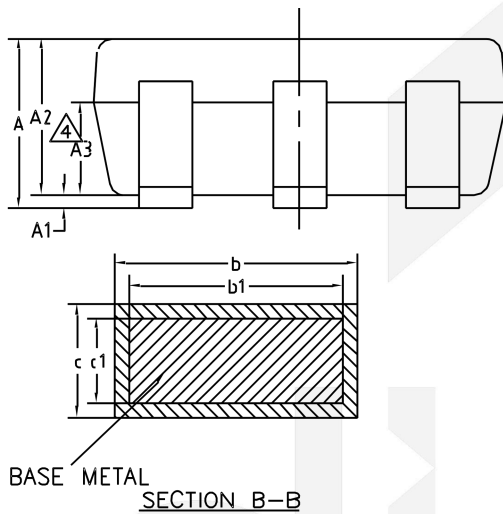
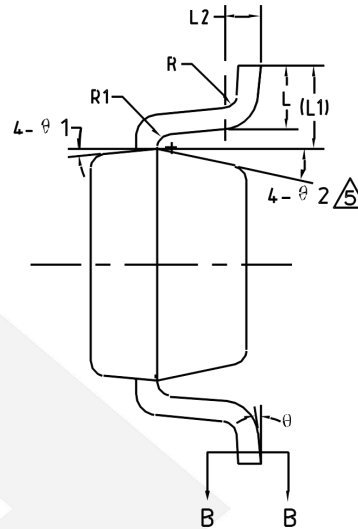
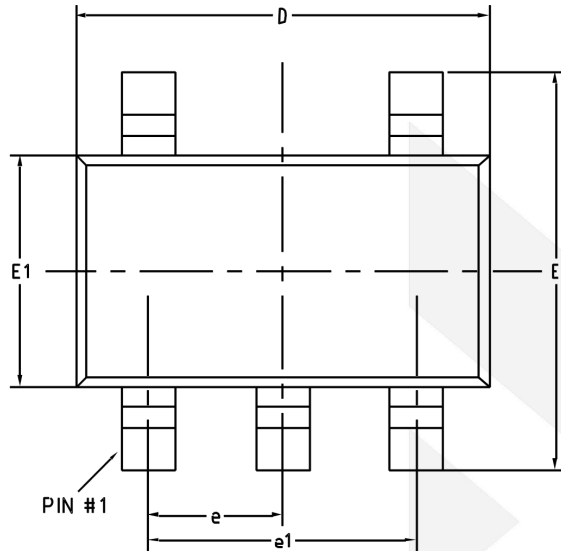
6. Physical Dimensions

6.1 SC70-5



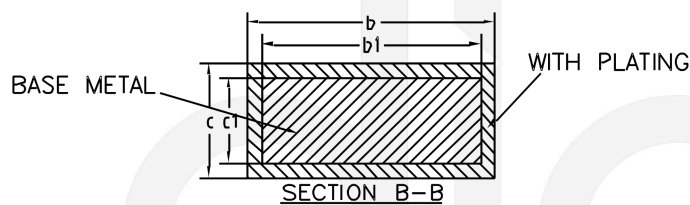
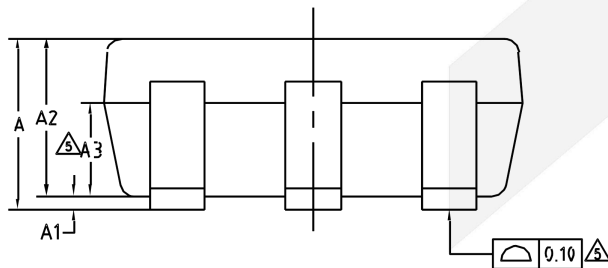
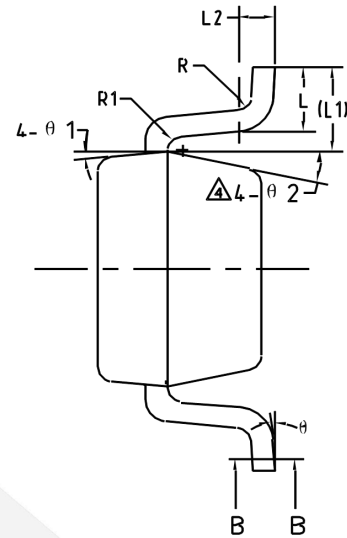
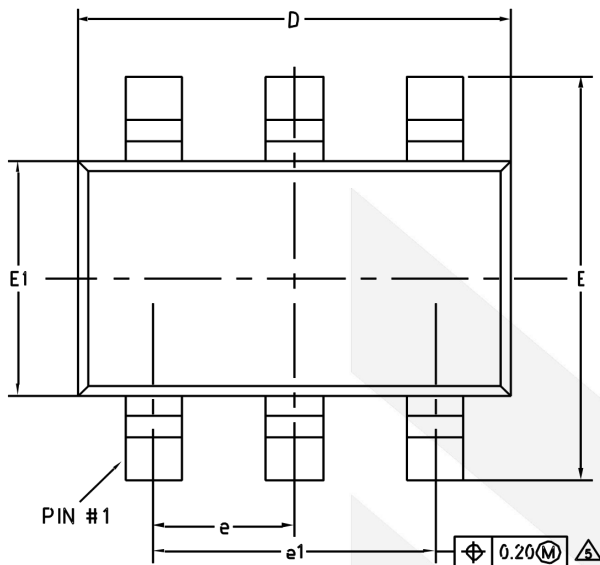
Common Dimensions (Units of Measure = Millimeter)			
Symbol	Min	Nom	Max
A	0.85	-	1.05
A1	0	-	0.10
A2	0.80	0.90	1.00
A3	0.47	0.52	0.57
b	0.22	-	0.29
b1	0.22	0.25	0.28
c	0.115	-	0.15
c1	0.115	0.13	0.14
D	2.02	2.07	2.12
E	2.20	2.30	2.40
E1	1.25	1.30	1.35
e	0.65 BSC		
e1	1.30 BSC		
L	0.28	0.33	0.38
L1	0.50 REF		
L2	0.15 BSC		
R	0.10	-	-
R1	0.10	-	0.25
theta	0°	-	8°
theta1	6°	9°	12°
theta2	6°	9°	12°

6.2 SOT23-5



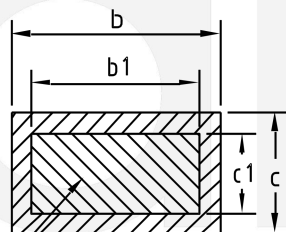
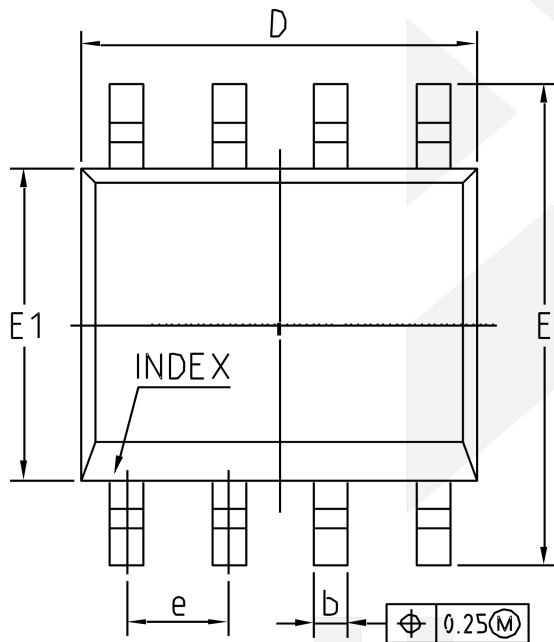
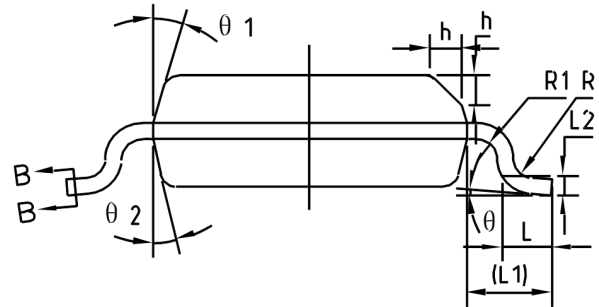
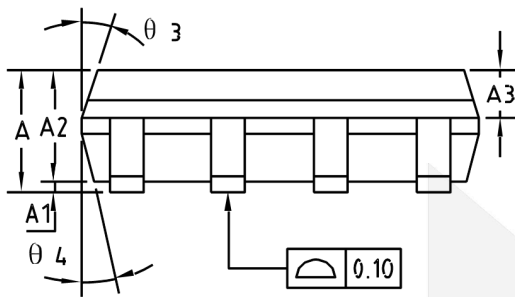
Common Dimensions (Units of Measure = Millimeter)			
Symbol	Min	Nom	Max
A	-	-	1.25
A1	0	-	0.15
A2	1.00	1.10	1.20
A3	0.60	0.65	0.70
b	0.36	-	0.50
b1	0.36	0.38	0.45
c	0.14	-	0.20
c1	0.14	0.15	0.16
D	2.826	2.926	3.026
E	2.60	2.80	3.00
E1	1.526	1.626	1.726
e	0.90	0.95	1.00
e1	1.80	1.90	2.00
L	0.35	0.45	0.60
L1	0.59 REF		
L2	0.25 BSC		
R	0.10	-	-
R1	0.10	-	0.25
θ	0°	-	8°
θ1	3°	5°	7°
θ2	6°	-	14°

6.3 SOT23-6



Common Dimensions (Units of Measure = Millimeter)			
Symbol	Min	Nom	Max
A	-	-	1.25
A1	0	-	0.15
A2	1.00	1.10	1.20
A3	0.60	0.65	0.70
b	0.36	-	0.50
b1	0.36	0.38	0.45
c	0.14	-	0.20
c1	0.14	0.15	0.16
D	2.826	2.926	3.026
E	2.60	2.80	3.00
E1	1.526	1.626	1.726
e	0.90	0.95	1.00
e1	1.80	1.90	2.00
L	0.35	0.45	0.60
L1	0.59 REF		
L2	0.25 BSC		
R	0.10	-	-
R1	0.10	-	0.25
θ	0°	-	8°
θ1	3°	5°	7°
θ2	6°	-	14°

6.4 SOIC-8

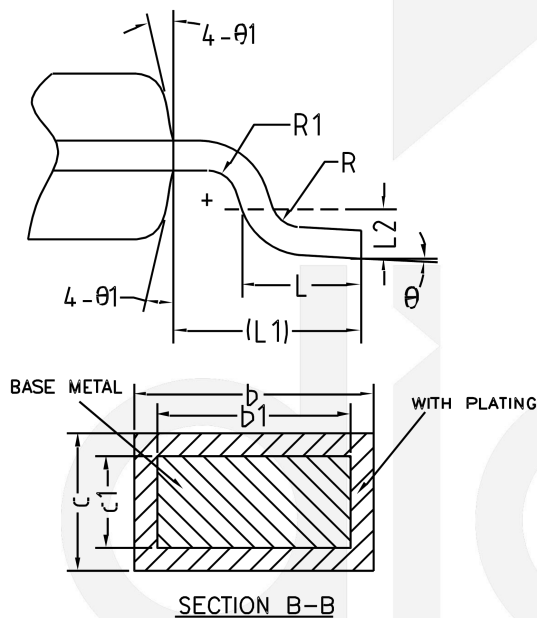
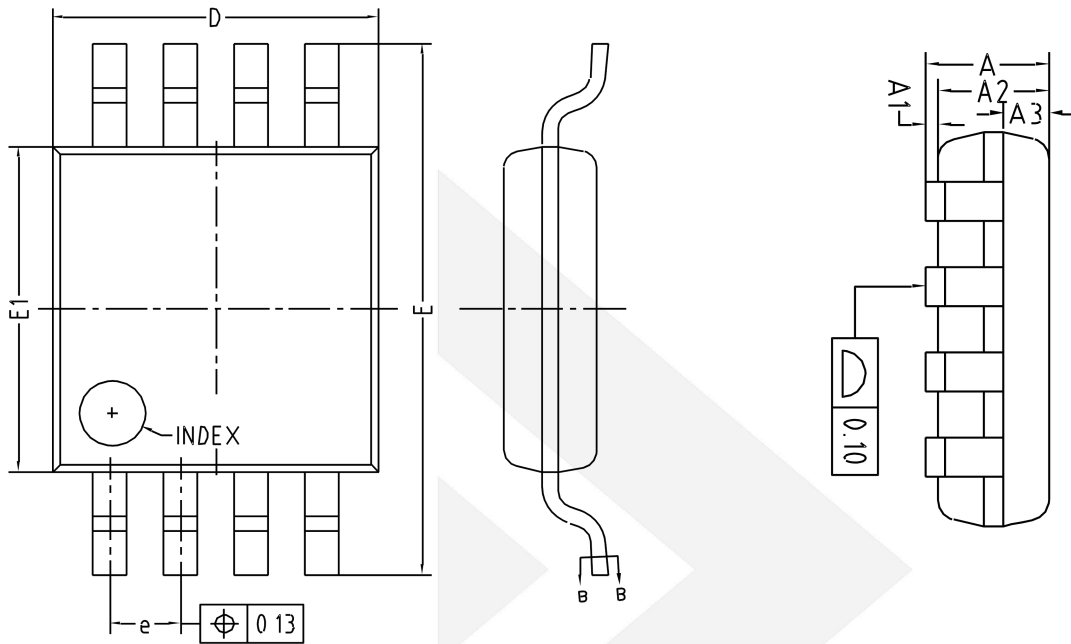


BASE METAL

SECTION B-B

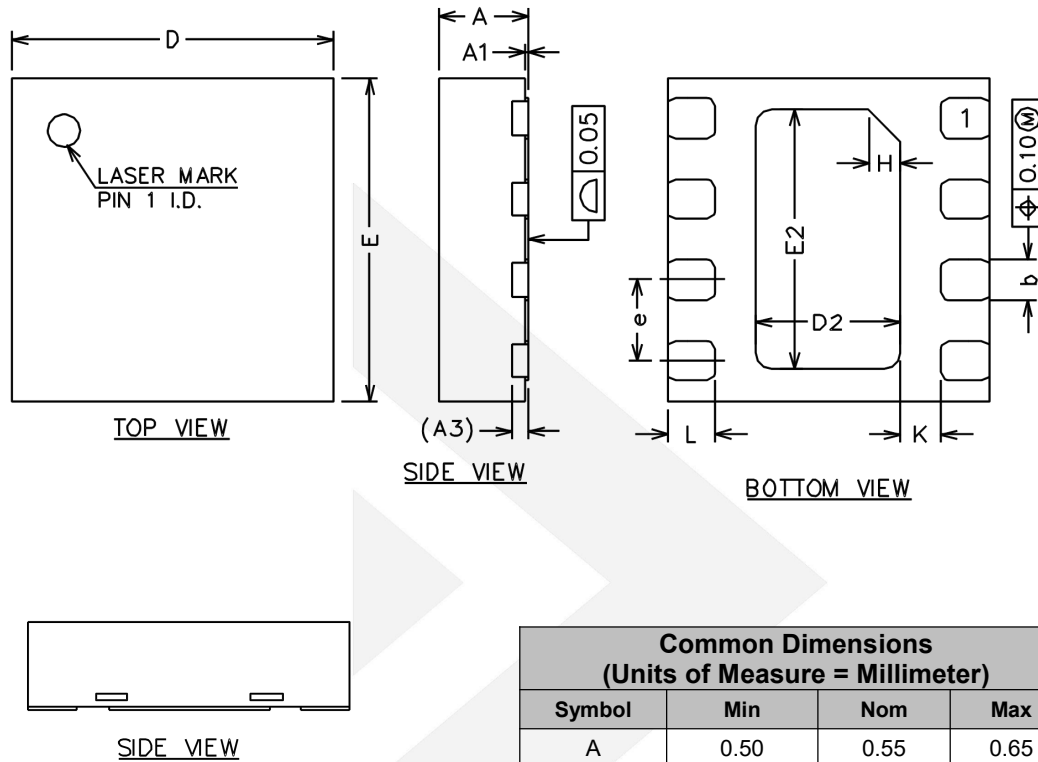
Common Dimensions (Units of Measure = Millimeter)			
Symbol	Min	Nom	Max
A	1.35	1.55	1.75
A1	0.10	0.15	0.25
A2	1.25	1.40	1.65
A3	0.50	0.60	0.70
b	0.38	-	0.51
b1	0.37	0.42	0.47
c	0.17	-	0.25
c1	0.17	0.20	0.23
D	4.80	4.90	5.00
E	5.80	6.00	6.20
E1	3.80	3.90	4.00
e	1.27 BSC		
L	0.45	0.60	0.80
L1	1.04 REF		
L2	0.25 BSC		
R	0.07	-	-
R1	0.07	-	-
h	0.30	0.40	0.50
θ	0°	-	8°
θ1	15°	17°	19°
θ2	11°	13°	15°
θ3	15°	17°	19°
θ4	11°	13°	15°

6.5 MSOP-8

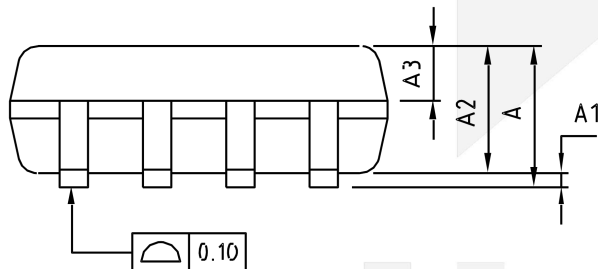
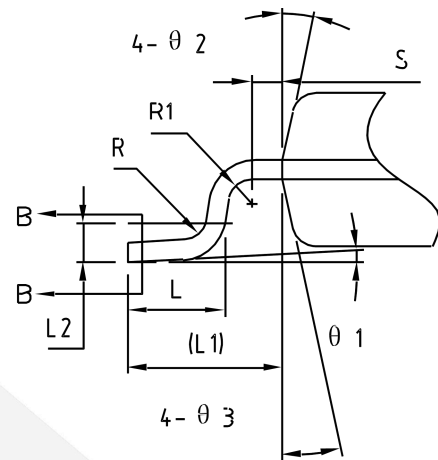
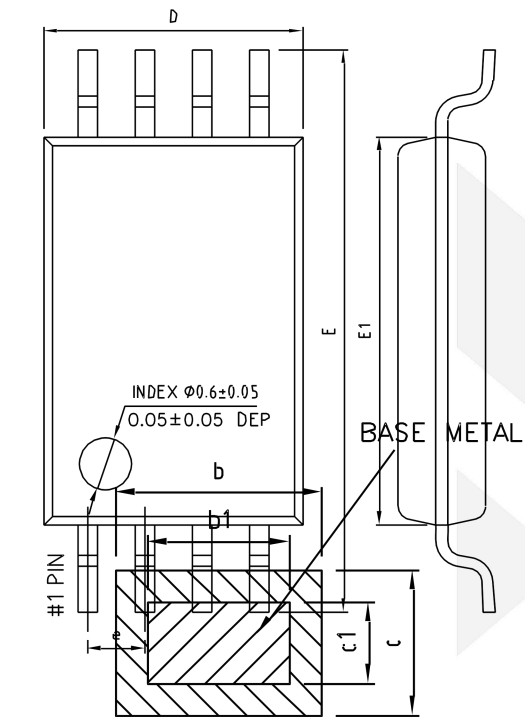


Common Dimensions (Units of Measure = Millimeter)			
Symbol	Min	Nom	Max
A	-	-	1.10
A1	0	-	0.15
A2	0.75	0.85	0.95
A3	0.25	0.35	0.39
b	0.28	-	0.37
b1	0.27	0.30	0.33
c	0.15	-	0.20
c1	0.14	0.15	0.16
D	2.90	3.00	3.10
E	4.70	4.90	5.10
E1	2.90	3.00	3.10
e	0.55	0.65	0.75
L	0.45	0.60	0.80
L1	0.95 REF		
L2	0.25 BSC		
R	0.07	-	-
R1	0.07	-	-
θ	0°	-	8°
θ1	9°	12°	15°

6.6 DFN2*2-8

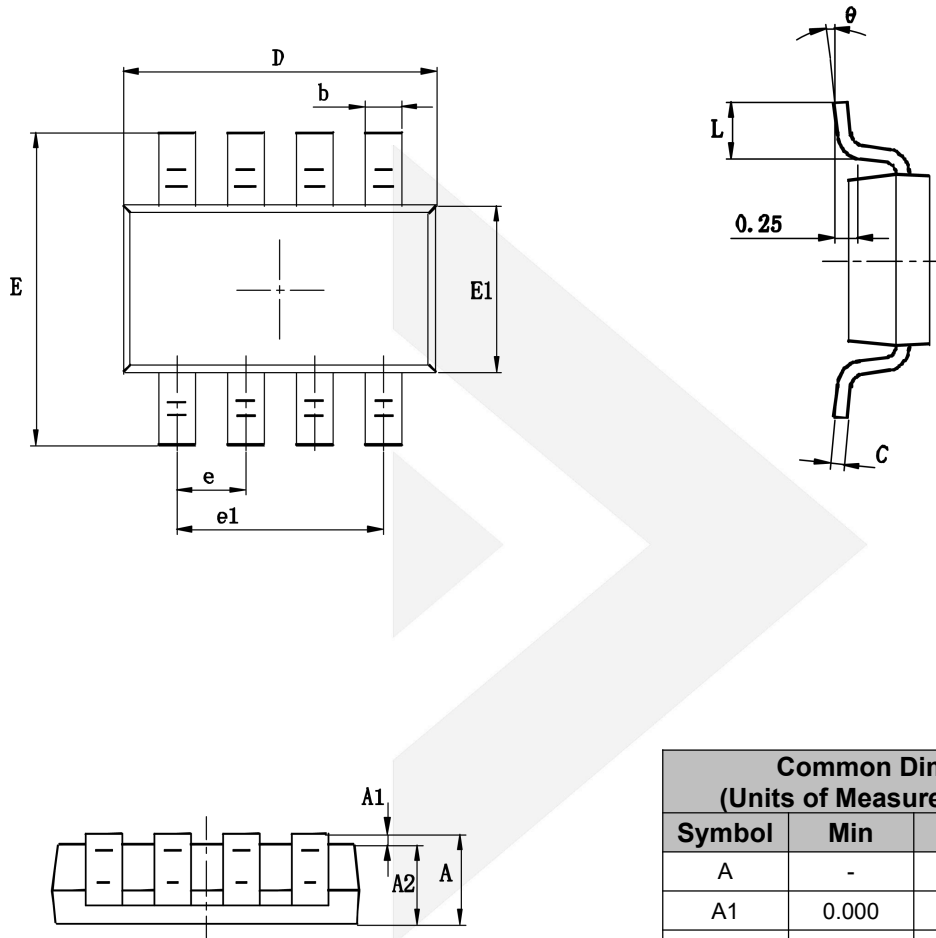


6.7 TSSOP-8



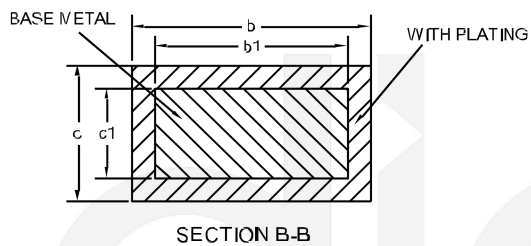
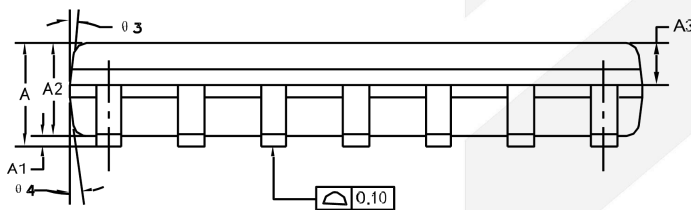
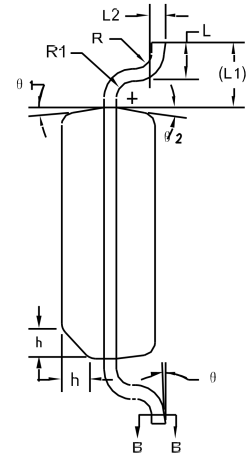
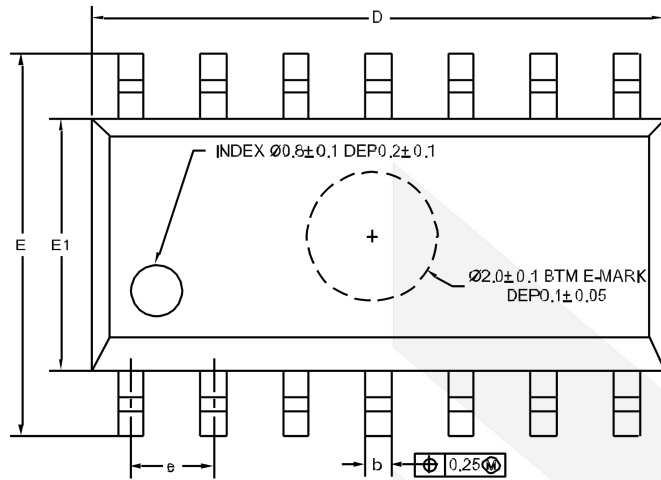
Common Dimensions (Units of Measure = Millimeter)			
Symbol	Min	Nom	Max
A	-	-	1.20
A1	0.05	-	0.15
A2	0.90	1.00	1.05
A3	0.34	0.44	0.54
b	0.20	-	0.28
b1	0.20	0.22	0.24
c	0.10	-	0.19
c1	0.10	0.13	0.15
D	2.83	2.93	3.03
E	6.20	6.40	6.60
E1	4.30	4.40	4.50
e	0.65 BSC		
L	0.45	0.60	0.75
L1	1.00 REF		
L2	0.25 BSC		
R	0.09	-	-
R1	0.09	-	-
S	0.20	-	-
θ1	0°	-	8°
θ2	10°	12°	14°
θ3	10°	12°	14°

6.8 TSOT23-8



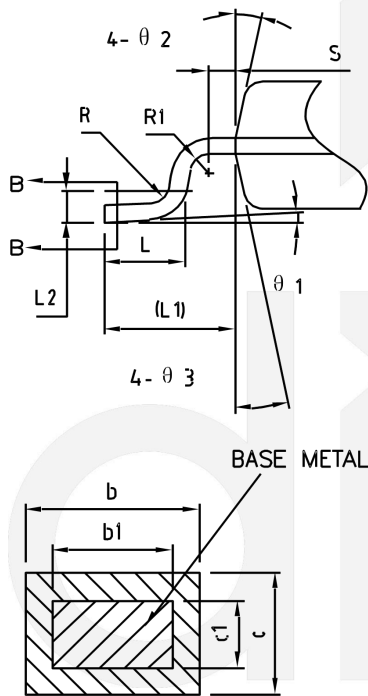
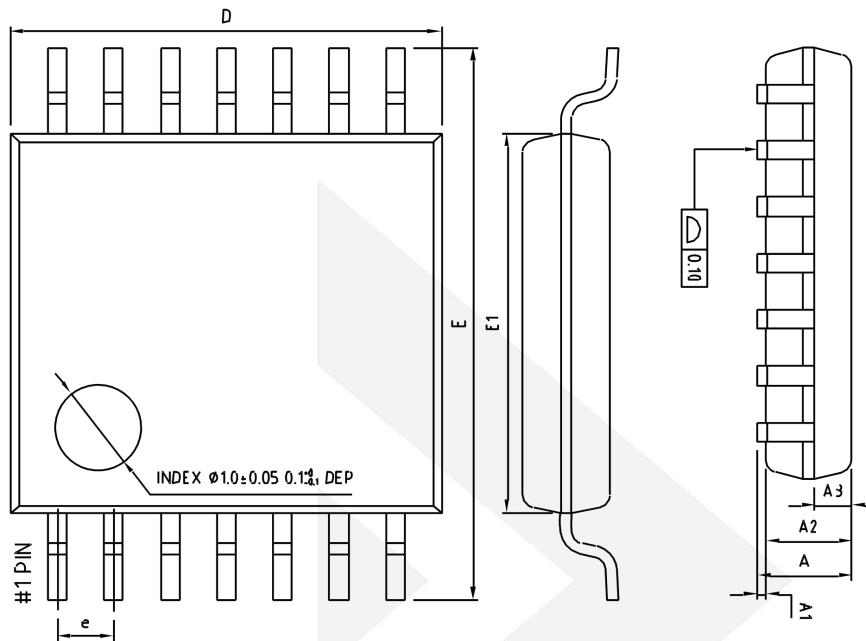
Common Dimensions (Units of Measure = Millimeter)			
Symbol	Min	Nom	Max
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A1	0.000	-	0.100
A2	0.700	-	0.800
b	0.300	-	0.500
c	0.080	-	0.200
D	2.820	-	3.020
E	2.650	-	2.950
E1	1.600	-	1.700
e	0.65BSC		
e1	1.90BSC		
L	0.300	-	0.600
θ	0°	-	8°

6.9 SOIC-14



Common Dimensions (Units of Measure = Millimeter)			
Symbol	Min	Nom	Max
A	1.35	1.60	1.75
A1	0.10	0.15	0.25
A2	1.25	1.45	1.65
A3	0.55	0.65	0.75
b	0.36	-	0.49
b1	0.35	0.40	0.45
c	0.17	-	0.25
c1	0.17	0.20	0.23
D	8.53	8.63	8.73
E	5.80	6.00	6.20
E1	3.80	3.90	4.00
e	1.27 BSC		
L	0.45	0.60	0.80
L1	1.04 RFE		
L2	0.25 BSC		
R	0.07	-	-
R1	0.07	-	-
h	0.30	0.40	0.50
θ	0°	-	8°
θ1	6°	8°	10°
θ2	6°	8°	10°
θ3	5°	7°	9°
θ4	5°	7°	9°

6.10 TSSOP-14



SECTION B-B

Common Dimensions
(Units of Measure = Millimeter)

Symbol	Min	Nom	Max
A	-	-	1.20
A1	0.05	-	0.15
A2	0.90	1.00	1.05
A3	0.34	0.44	0.54
b	0.20	-	0.28
b1	0.20	0.22	0.24
c	0.10	-	0.19
c1	0.10	0.13	0.15
D	4.86	4.96	5.06
E	6.20	6.40	6.60
E1	4.30	4.40	4.50
e	0.65 BSC		
L	0.45	0.60	0.75
L1	1.00 REF		
L2	0.25 BSC		
R	0.09	-	-
R1	0.09	-	-
S	0.20	-	-
θ1	0°	-	8°
θ2	10°	12°	14°
θ3	10°	12°	14°



DIO20721/1D/2/4

Single/Dual/Quad channel RRIO 10 MHz Amplifier

CONTACT US

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For additional product information, or full datasheet, please contact with our Sales Department or Representatives.

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